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ZXTN2007Z

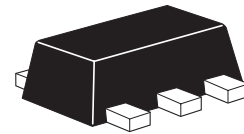
30V NPN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

SUMMARY

$BV_{CEO} = 30V$; $R_{SAT} = 23m\Omega$; $I_C = 6.0A$

DESCRIPTION

Packaged in the SOT89 outline this new low saturation 30V NPN transistor offers extremely low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.



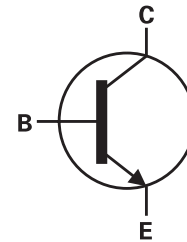
SOT89

FEATURES

- Extremely low equivalent on-resistance; $R_{SAT} = 23m\Omega$ at 6.5A
- 6 amps continuous current
- Up to 20 amps peak current
- Very low saturation voltages
- Excellent h_{FE} characteristics up to 20 amps

APPLICATIONS

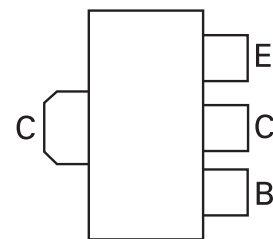
- DC - DC converters
- MOSFET gate drivers
- Charging circuits
- Power switches
- Motor control



ORDERING INFORMATION

DEVICE	REEL SIZE	TAPE WIDTH	QUANTITY PER REEL
ZXTN2007ZTA	7"	12mm embossed	1000 units

PINOUT



TOP VIEW

DEVICE MARKING

849

ZXTN2007Z

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-base voltage	BV_{CBO}	80	V
Collector-emitter voltage	BV_{CEO}	30	V
Emitter-base voltage	BV_{EBO}	7	V
Continuous collector current ^(a)	I_C	6	A
Peak pulse current	I_{CM}	20	A
Power dissipation at $T_A = 25^\circ\text{C}$ ^(a)	P_D	1.5	W
Linear derating factor		12	mW/ $^\circ\text{C}$
Power dissipation at $T_A = 25^\circ\text{C}$ ^(b)	P_D	2.1	W
Linear derating factor		16.8	mW/ $^\circ\text{C}$
Operating and storage temperature range	T_j, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL RESISTANCE

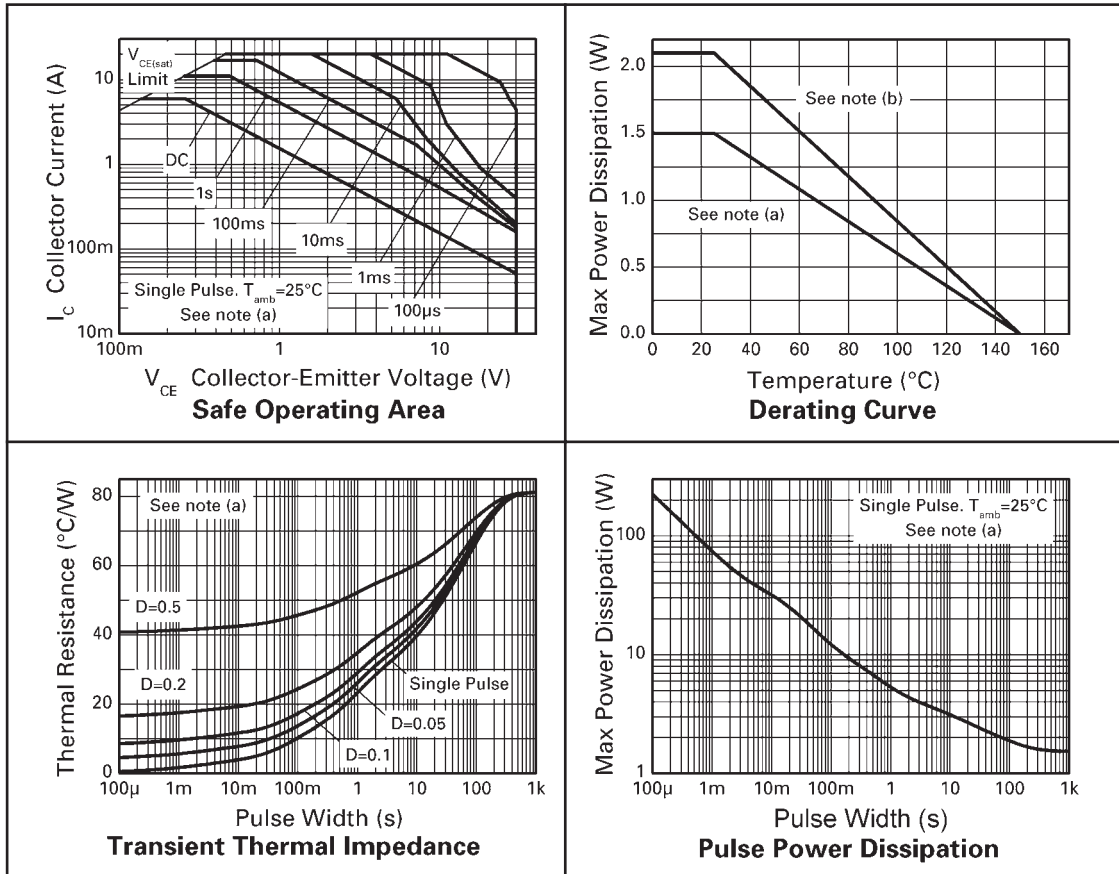
PARAMETER	SYMBOL	VALUE	UNIT
Junction to ambient ^(a)	$R_{\theta JA}$	83	$^\circ\text{C}/\text{W}$
Junction to ambient ^(b)	$R_{\theta JA}$	60	$^\circ\text{C}/\text{W}$

NOTES

- (a) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
(b) For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

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CHARACTERISTICS



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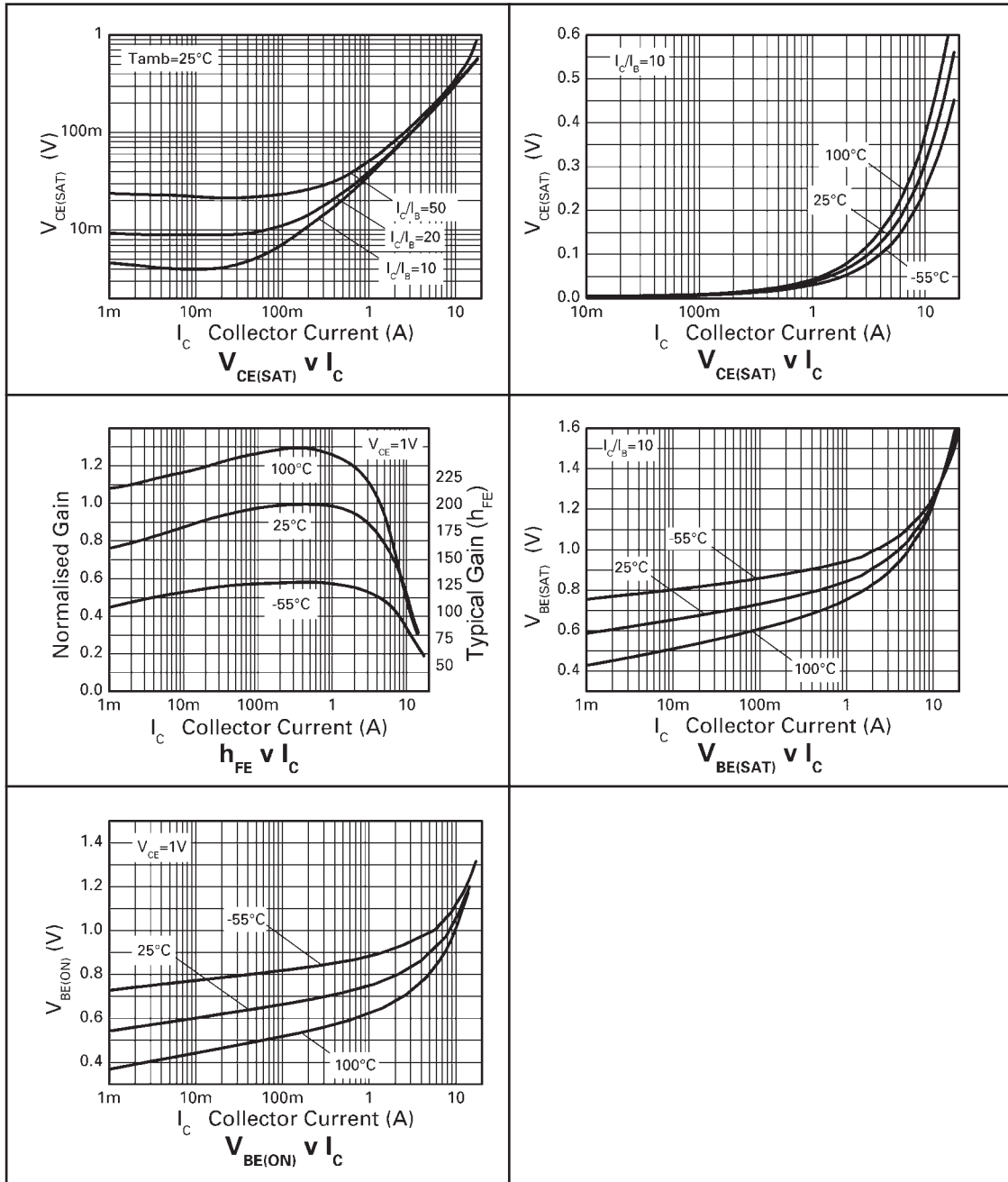
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-base breakdown voltage	BV_{CBO}	80	125		V	$I_C=100\mu\text{A}$
Collector-emitter breakdown voltage	BV_{CER}	80	125		V	$I_C=1\mu\text{A}$, $R_B\leq 1\text{k}\Omega$
Collector-emitter breakdown voltage	BV_{CEO}	30	40		V	$I_C=10\text{mA}^*$
Emitter-base breakdown voltage	BV_{EBO}	7	8.1		V	$I_E=100\mu\text{A}$
Collector cut-off current	I_{CBO}			50 0.5	nA μA	$V_{CB}=70\text{V}$ $V_{CB}=70\text{V}$, $T_{amb}=100^{\circ}\text{C}$
Collector cut-off current	I_{CER} $R\leq 1\text{k}\Omega$			100 0.5	nA μA	$V_{CB}=70\text{V}$ $V_{CB}=70\text{V}$, $T_{amb}=100^{\circ}\text{C}$
Emitter cut-off current	I_{EBO}			10	nA	$V_{EB}=6\text{V}$
Collector-emitter saturation voltage	$V_{CE(SAT)}$		22 25 40 90 150	35 45 60 115 190	mV	$I_C=0.5\text{A}$, $I_B=20\text{mA}^*$ $I_C=1\text{A}$, $I_B=100\text{mA}^*$ $I_C=1\text{A}$, $I_B=20\text{mA}^*$ $I_C=2\text{A}$, $I_B=20\text{mA}^*$ $I_C=6.5\text{A}$, $I_B=300\text{mA}^*$
Base-emitter saturation voltage	$V_{BE(SAT)}$		1000	1100	mV	$I_C=6.5\text{A}$, $I_B=300\text{mA}^*$
Base-emitter turn-on voltage	$V_{BE(ON)}$		890	1000	mV	$I_C=6.5\text{A}$, $V_{CE}=1\text{V}^*$
Static forward current transfer ratio	h_{FE}	100 100 100 20	175 200 150 30	300		$I_C=10\text{mA}$, $V_{CE}=1\text{V}^*$ $I_C=1\text{A}$, $V_{CE}=1\text{V}^*$ $I_C=7\text{A}$, $V_{CE}=1\text{V}^*$ $I_C=20\text{A}$, $V_{CE}=1\text{V}^*$
Transition frequency	f_T		140		MHz	$I_C=100\text{mA}$, $V_{CE}=10\text{V}$ $f=50\text{MHz}$
Output capacitance	C_{OBO}		48		pF	$V_{CB}=10\text{V}$, $f=1\text{MHz}^*$
Switching times	t_{ON} t_{OFF}		37 425		ns	$I_C=1\text{A}$, $V_{CC}=10\text{V}$, $I_{B1}=-I_{B2}=100\text{mA}$

* Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$; duty cycle $\leq 2\%$.

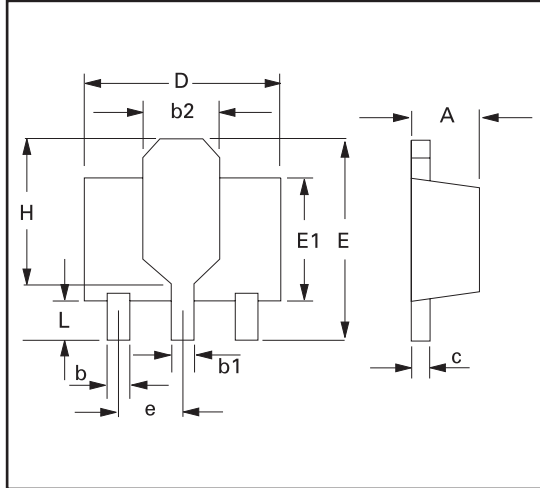
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TYPICAL CHARACTERISTICS

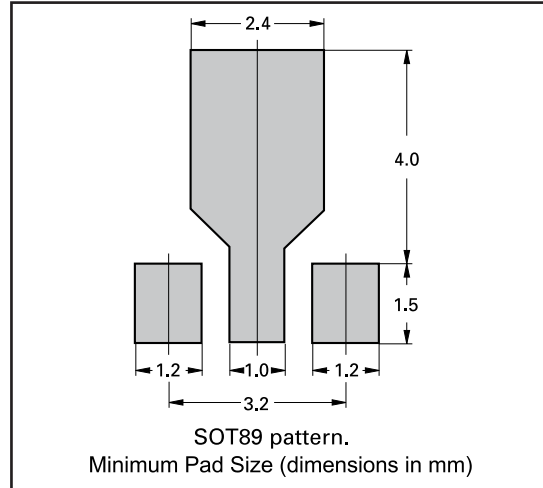


ZXTN2007Z

PACKAGE OUTLINE



PAD LAYOUT DETAILS



Controlling dimensions are in millimeters. Approximate conversions are given in inches

PACKAGE DIMENSIONS

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	1.40	1.60	0.550	0.630	e	1.40	1.50	0.055	0.059
b	0.38	0.48	0.015	0.019	E	3.75	4.25	0.150	0.167
b1	-	0.53	-	0.021	E1	-	2.60	-	0.102
b2	1.50	1.80	0.060	0.071	G	2.90	3.00	0.114	0.118
c	0.28	0.44	0.011	0.017	H	2.60	2.85	0.102	0.112
D	4.40	4.60	0.173	0.181	-	-	-	-	-

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